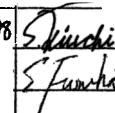
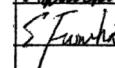


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DRAWN	DATE	APPROVED
CHECKED	2-1998	  

DWG NO.

Fuji Electric Co.,Ltd.

MS5F4292

1/2

Revised Records

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Date	Classifi- cation	Ind.	Content	Applied date	Drawn	Checked	Approved
April- 1-1993	enactment	—	—	Issued date ?	—	S. Jankota	S. Jankota

Fuji Electric Co., Ltd.

DWG.NO.

MS5 F4292

904-004-06

- 2 Construction
Self-Isolation Structure
Output Part; N-channel enhancement mode power MOSFET
- 3 Application
For switching
- 4 Outview
SOP-8(EIAJ SC-87) Outview See to 6/12 page)
- 5 Absolute maximum ratings (at $T_j=25^\circ\text{C}$, unless otherwise specified.)

Description	Symbol	Characteristics	Unit	Conditions
Drain-source voltage	V_{DSS}	4 0	V	D C
Gate-source voltage	V_{GSS}	D C - 0.3 ~ 7.0	V	D C
Continuous drain current	I_D	1	A	—
Maximum power dissipation	P_D	1.5	W	‡
Operating junction temperature	T_j	150	$^\circ\text{C}$	—
Storage temperature range	T_{stg}	- 55 ~ 150	$^\circ\text{C}$	—

‡ Surface Mounted on 1000mm²PCR(FR-4)

- 6 Electrical characteristics (at $T_j=25^\circ\text{C}$, unless otherwise specified.)

Description	Symbol	Conditions	Characteristics			Unit
			Min.	Typ.	Max.	
Drain-source clamp voltage	V_{DSS}	$I_D = 1 \text{ mA}$ $V_{GS} = 0 \text{ V}$	4 0		6 0	V
Gate threshold voltage	$V_{GS(th)}$	$I_D = 10 \text{ mA}$ $V_{DS} = 13 \text{ V}$	1.0		2.8	V
Operation gate voltage	$V_{GS(p)}$		3.5		7.0	V
Zero gate voltage drain current	I_{DSS}	$V_{DS} = 30 \text{ V}$ $V_{GS} = 0 \text{ V}$			1.0	mA
Gate-source leakage current	$I_{GS(n)}$	‡	$V_{GS} = 5 \text{ V}$		5 0 0	μA
	$I_{GS(un)}$	‡‡			8 0 0	μA
Drain-source on-state resistance	$R_{DS(on)}$	$I_D = 0.5 \text{ A}$ $V_{GS} = 5 \text{ V}$			6 0 0	$\text{m}\Omega$

* Under normal operation

** Under self protection

Description	Symbol	Conditions	Characteristics			Unit
			Min.	Typ.	Max.	
Turn-on time	t_{on}	$V_{ds} = 13\text{ V}$ $I_o = 0.5\text{ A}$ $V_{gs} = 5\text{ V}$			50	μs
Turn-off time	t_{off}				50	μs
Over-temperature protection	T_{trip}	$V_{gs} = 5\text{ V}$	150			$^{\circ}\text{C}$
Short circuit protection	I_{oc}	$V_{gs} = 5\text{ V}$	1			A
Single pulse inductive load switch-off energy dissipation	E_{cl}	$T_J = 150\text{ }^{\circ}\text{C}$	25			mJ

7. Thermal resistance

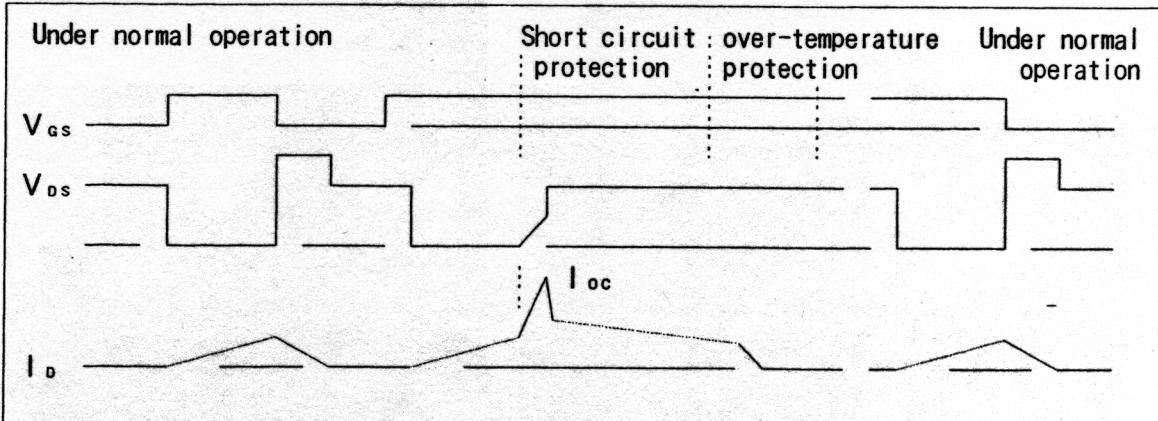
Description	Symbol	Conditions	Characteristics			Unit
			Min.	Typ.	Max.	
Thermal resistance	$R_{th(j-a)}$	Junction-ambient *			83	$^{\circ}\text{C/W}$

* Surface Mounted on 1000mm²PCB(FR-4)

8. Electrostatic discharge

Description	Conditions	Characteristics			Unit
		Min.	Typ.	Max.	
Drain-source	150 pF, 15.0 Ω	± 15			kV
Gate-source		± 0.5			kV

9. Timing chart



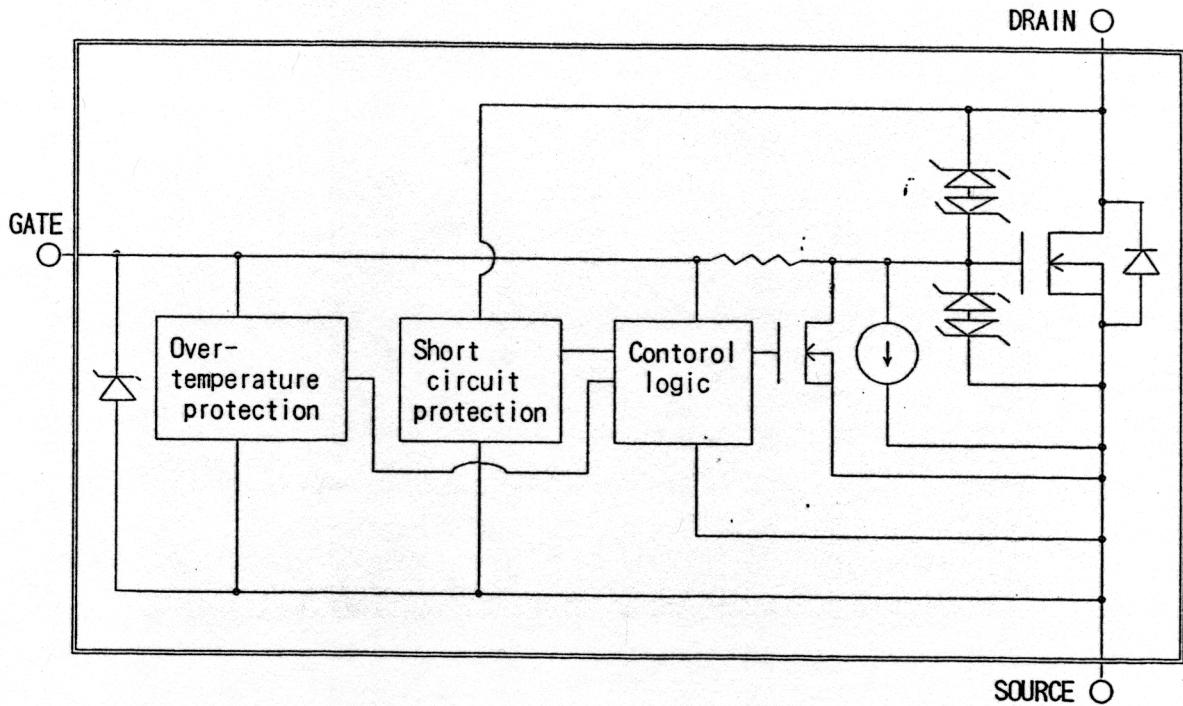
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H04-004-03

10. Block diagram



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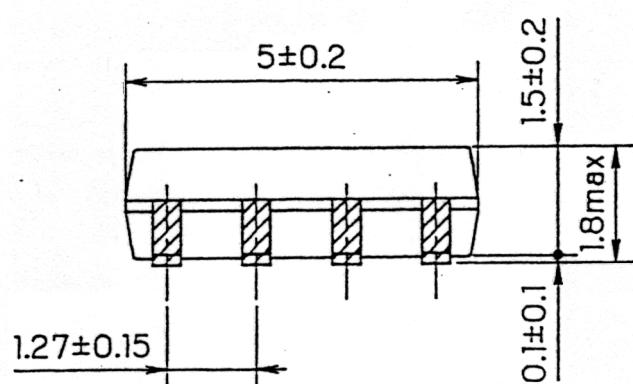
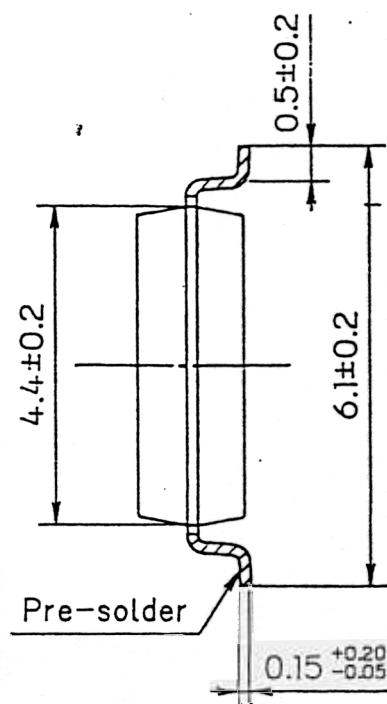
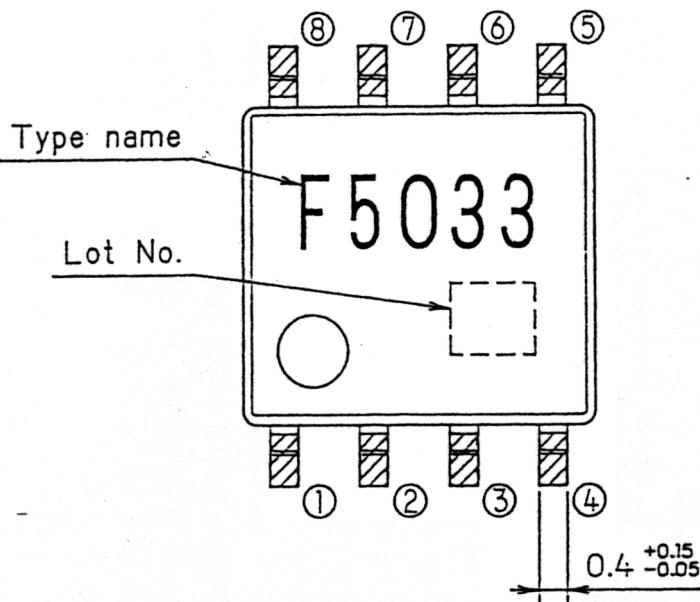
H04-700-703

5/2

FUJI INTELLIGENT POWER MOS FET

TYPE : F5033

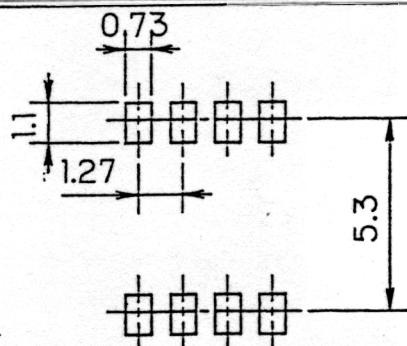
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CONNECTION

- ① SOURCE 1
- ② GATE 1
- ③ SOURCE 2
- ④ GATE 2
- ⑤ ⑥ DRAIN 2
- ⑦ ⑧ DRAIN 1

RECOMMENDED PATTERN OF SOLDERING PADS.



EIAJ : SC-87

DIMENSIONS ARE IN MILLIMETERS.

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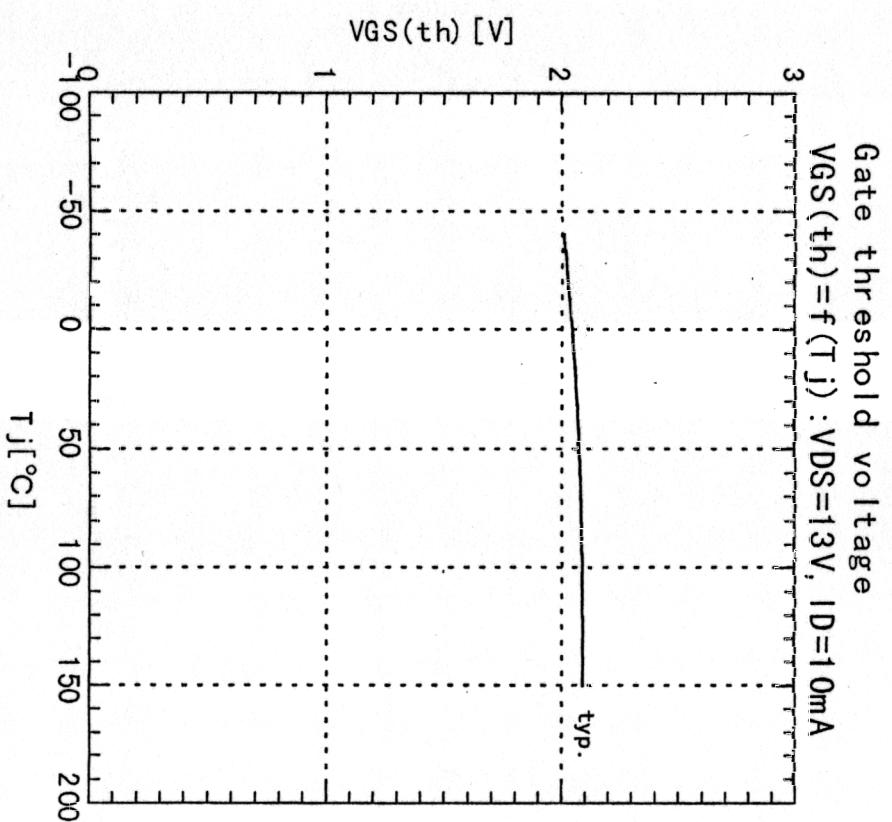
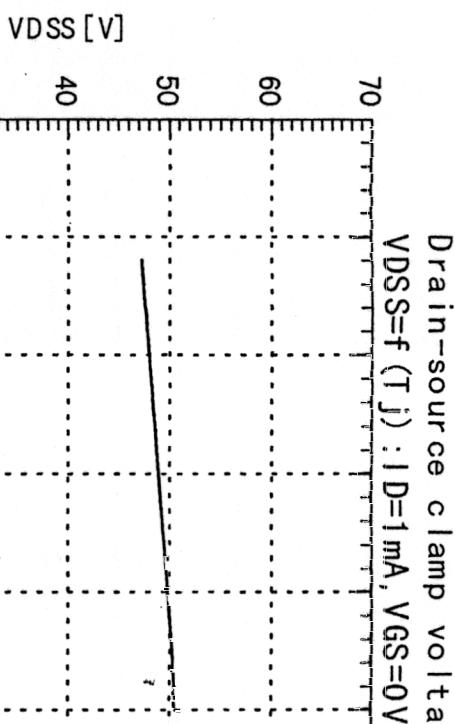
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H04-004-03

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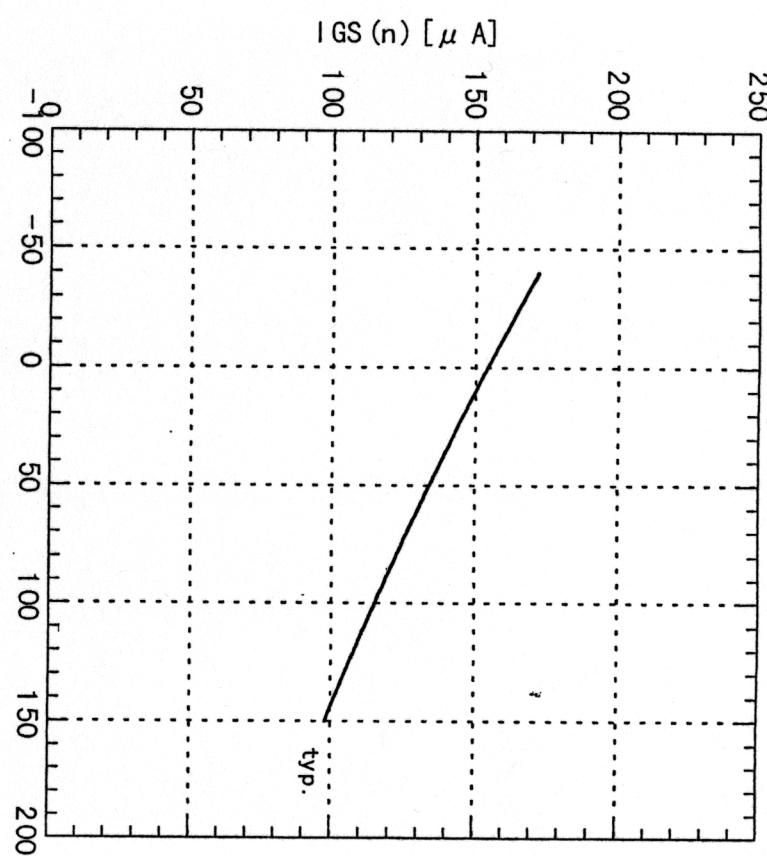
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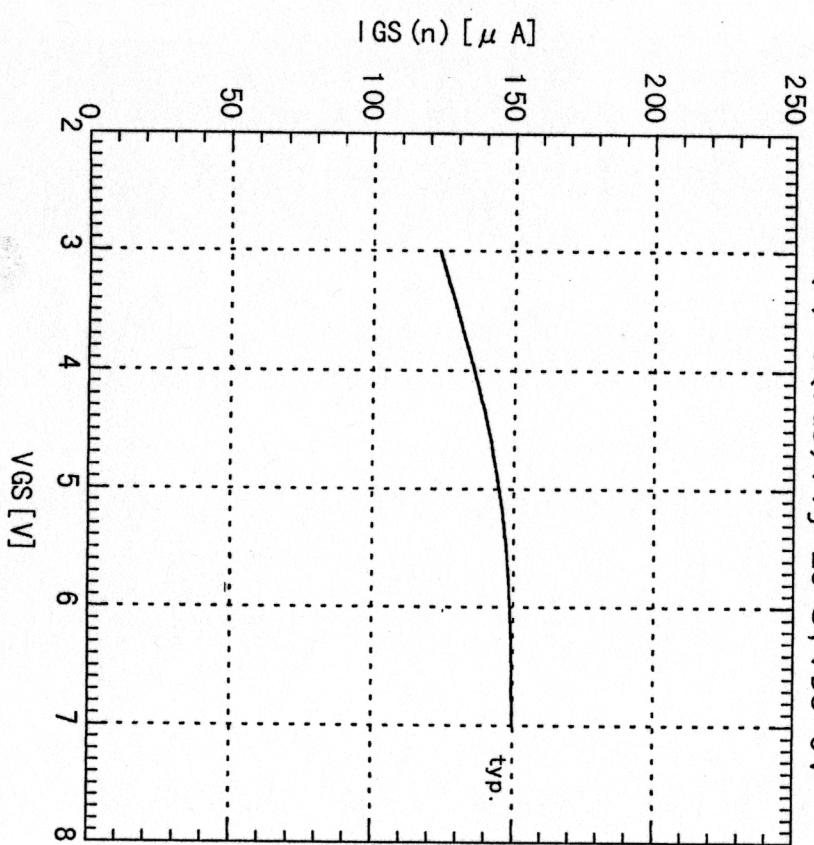
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Gate-source leakage current
 $I_{GS(n)} = f(T_j) : V_{GS} = 5V, V_{DS} = 0V$



Gate-source leakage current

$$I_{GS(n)} = f(V_{GS}) : T_j = 25^{\circ}C, V_{DS} = 0V$$



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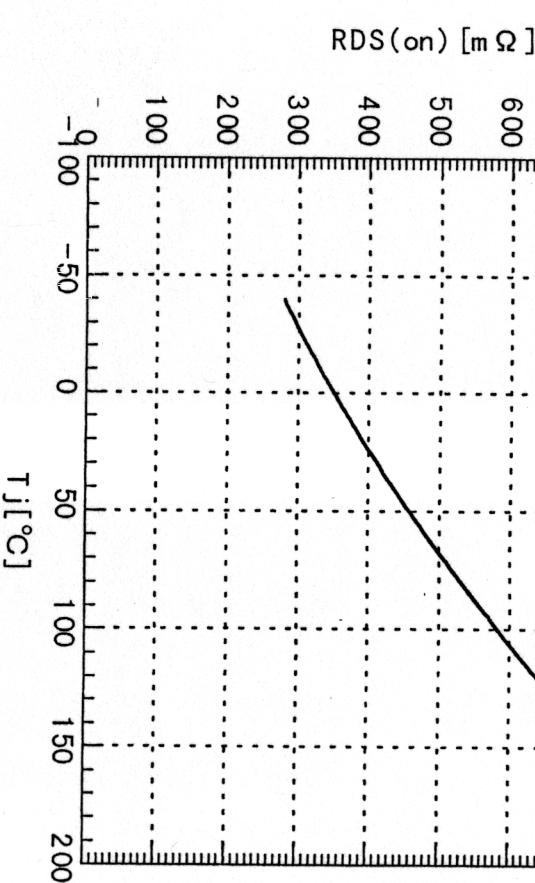
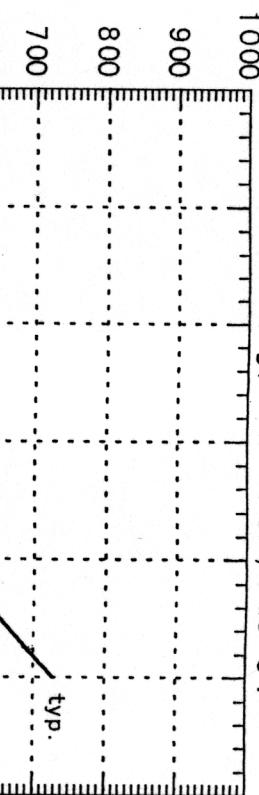
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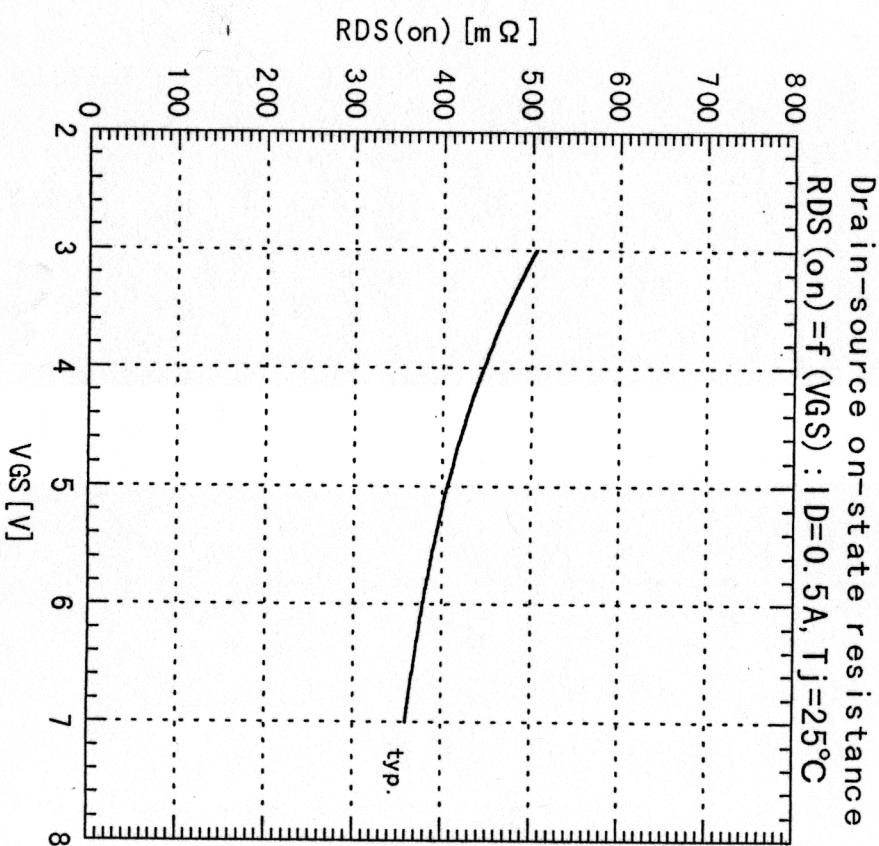
H04-004-03

Drain-source on-state resistance

$$RDS(on) = f(T_j) : ID=0.5A, VGS=5V$$

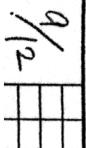


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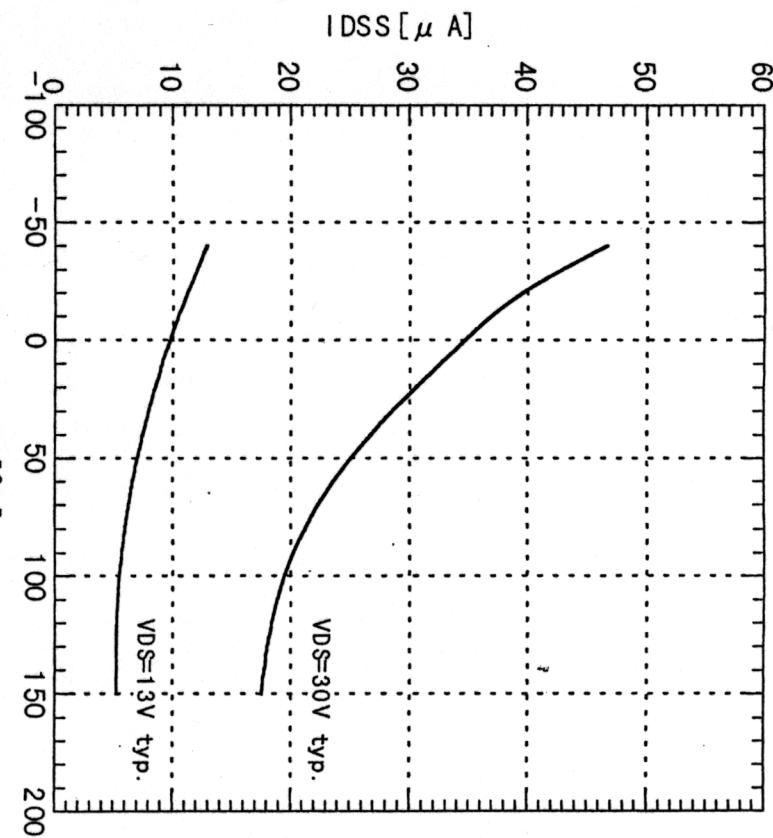
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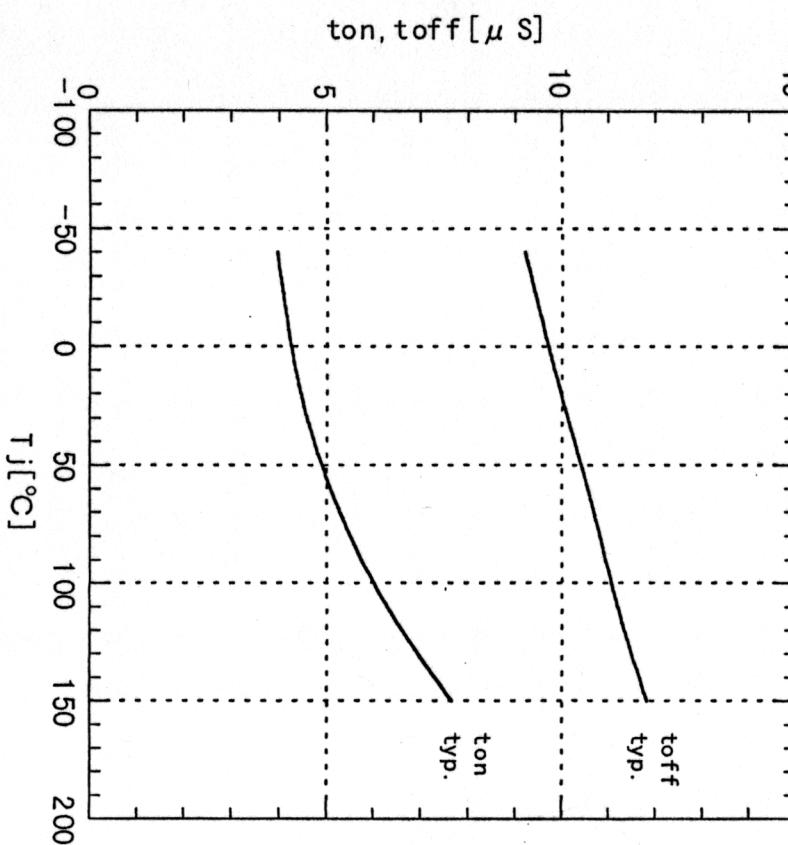


H04-004-03

Zero gate voltage drain current
 $ID_{SS}=f(T_j)$: $V_{DS}=13V, 30V, V_{GS}=0V$



Turn-on time, Turn-off time
 $t_{on}, t_{off}=f(T_j)$: $V_{DS}=13V, ID=0.5A, V_{GS}=5V$



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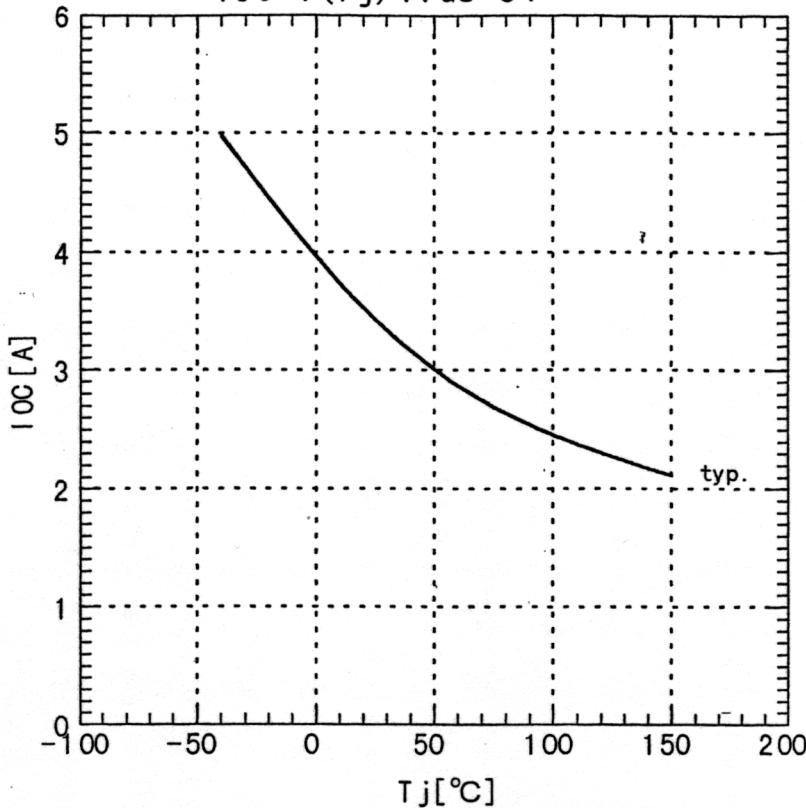
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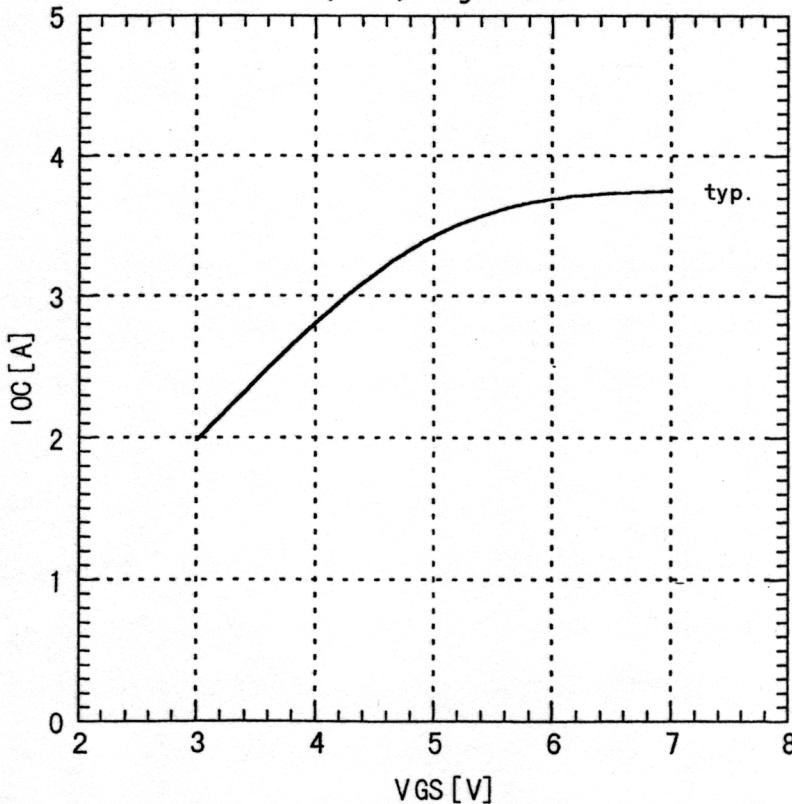
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10
1/2
mm, mm, mm

Short circuit protection
 $I_{OC} = f(T_j)$: VGS = 5V

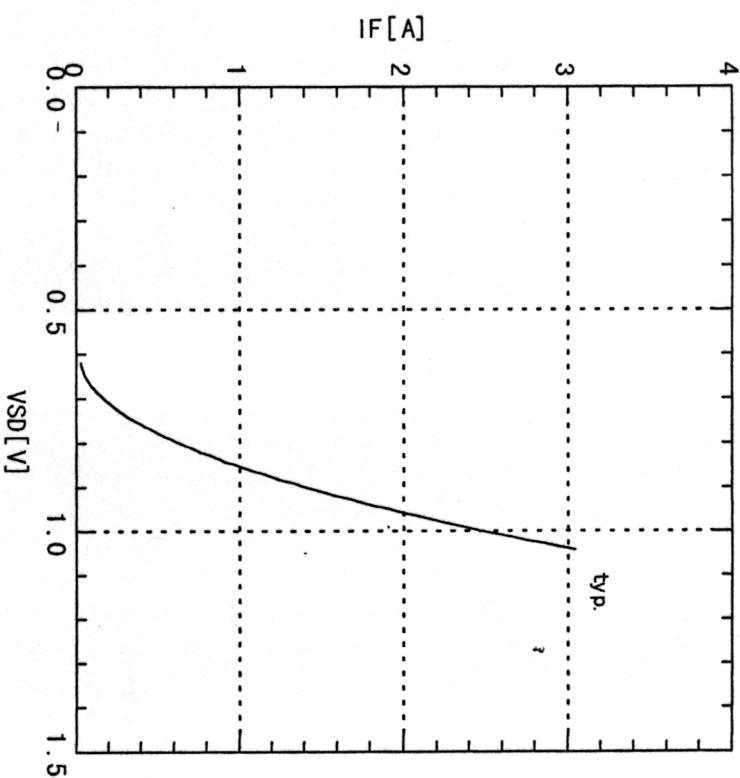


Short circuit protection
 $I_{OC} = f(VGS)$: $T_j = 25^{\circ}\text{C}$

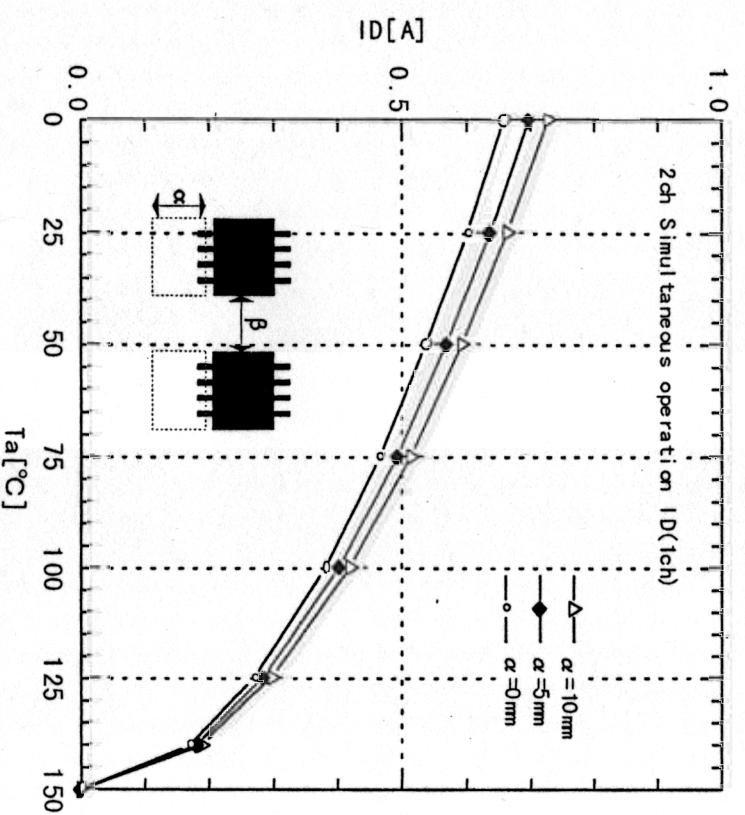


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Forward characteristic of reverse of diode
 $|I_F=f(VSD)|$: $VGS=0V$



Continuous drain current VS Ambient temperature
 $|ID=f(Ta)|$: Mounting Pad Size (β) = 5mm



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$\frac{12}{12}$
 μΩ_A-μΩ_B-μΩ_C